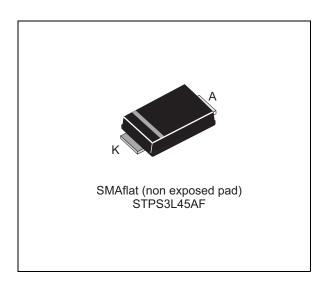




## Power Schottky rectifier

Datasheet - production data



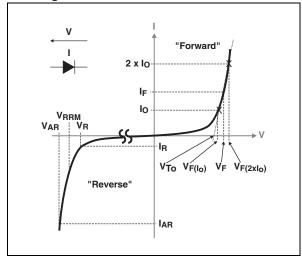
#### **Features**

- · Negligible switching losses
- Low thermal resistance
- Low forward voltage drop
- · Avalanche capability specified

### **Description**

Schottky rectifier suited for switched mode power supplies and high frequency DC to DC converters. Packaged in a tiny SMAflat package, this device has been optimized for use in compact chargers.

Figure 1. Electrical characteristics<sup>(a)</sup>



**Table 1. Device summary** 

Symbol	value
I <sub>F(AV)</sub>	3 A
V <sub>RRM</sub>	45 V
T <sub>j</sub> (max)	150 °C
V <sub>F</sub> (typ)	0.462 V

a.  $V_{ARM}$  and  $I_{ARM}$  must respect the reverse safe operating area defined in *Figure 11*.  $V_{AR}$  and  $I_{AR}$  are pulse measurements ( $t_p < 10~\mu s$ ).  $V_R$ ,  $I_R$ ,  $V_{RRM}$  and  $V_F$ , are static characteristics

Characteristics STPS3L45AF

#### 1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Test conditions	Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		45	V
I <sub>F(AV)</sub>	Average forward current	$T_L = 120  ^{\circ}\text{C}  \delta = 0.5$	3	Α
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoidal	75	Α
P <sub>ARM</sub> <sup>(1)</sup>	Repetitive peak avalanche power	t <sub>p</sub> = 10 μs Tj = 125 °C	70	W
V <sub>ARM</sub> <sup>(2)</sup>	Maximum repetitive peak avalanche voltage	t <sub>p</sub> < 10 μs, Tj < 125 °C, I <sub>AR</sub> < 1.4 A	50	٧
V <sub>ASM</sub> <sup>(2)</sup>	Maximum single pulse peak avalanche voltage	t <sub>p</sub> < 10 μs, Tj < 125 °C, I <sub>AR</sub> < 1.4 A	50	V
T <sub>stg</sub>	Storage temperature range		-65 to + 175	°C
T <sub>j</sub>	Operating junction temperature (3)		150	°C

For pulse time duration deratings, please refer to Figure 4. More details regarding the avalanche energy
measurements and diode validation in the avalanche are provided in the STMicroelectronics Application
notes AN1768, "Admissible avalanche power of Schottky diodes" and AN2025, "Converter improvement
using Schottky rectifier avalanche specification".

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-l)</sub>	Thermal resistance junction to lead		°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	$V_R = V_{RRM}$	80	300	μA
'R`	Reverse leakage current	T <sub>j</sub> = 125 °C		66	135	mA
V <sub>E</sub> <sup>(1)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 3 A	0.462	0.57	V
VF` ′	Tronward vollage drop	T <sub>j</sub> = 125 °C	IF - 3 A	0.41	0.51	

<sup>1.</sup> Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses use the following equation:

$$P = 0.36 \times I_{F(AV)} + 0.05 I_{F}^{2}(RMS)$$

<sup>2.</sup> Refer to Figure 11

<sup>3.</sup>  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

STPS3L45AF Characteristics

Figure 2. Average forward power dissipation versus average forward current

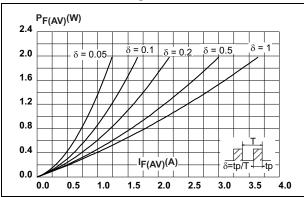


Figure 3. Average forward current versus ambient temperature ( $\delta = 0.5$ )

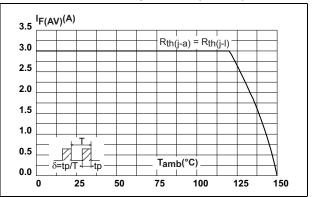
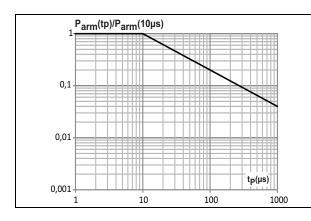


Figure 4. Normalized avalanche power derating versus pulse duration

Figure 5. Relative variation of thermal impedance junction to lead versus pulse duration



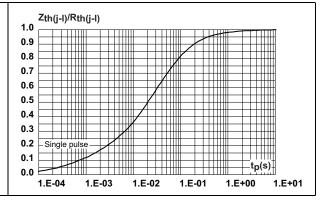


Figure 6. Reverse leakage current versus reverse voltage applied (typical values)

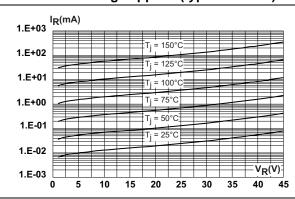
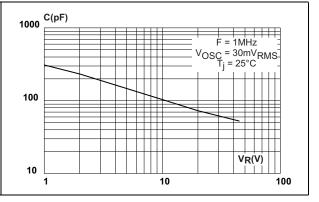


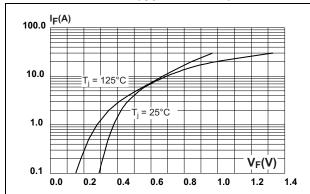
Figure 7. Junction capacitance versus reverse voltage applied (typical values)



Characteristics STPS3L45AF

Figure 8. Forward voltage drop versus forward current (typical values)

Figure 9. Forward voltage drop versus forward current (maximum values)



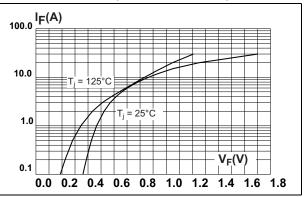
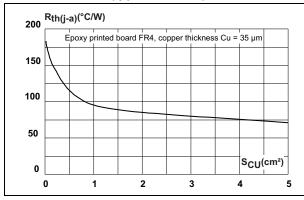
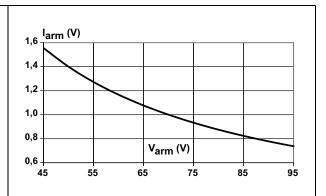


Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (typical values)

Figure 11. Reverse safe operating area ( $t_p$  < 10 µs and  $T_j$  < 125 °C)





## 2 Package information

- Epoxy meets UL94,V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

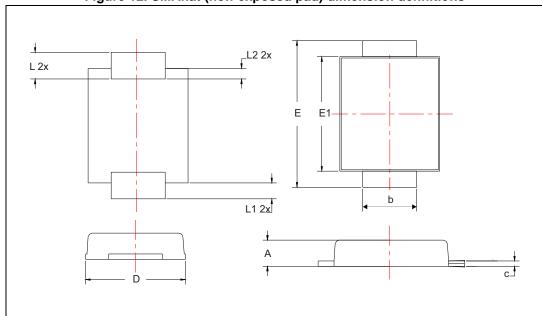


Figure 12. SMAflat (non-exposed pad) dimension definitions

Table 5. SMAflat (non-exposed pad) dimension values

	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.90		1.10	0.035		0.043
b	1.25		1.65	0.049		0.065
С	0.15		0.40	0.006		0.016
D	2.25		2.95	0.088		0.116
Е	4.80		5.60	0.189		0.220
E1	3.95		4.60	0.155		0.181
L	0.75		1.50	0.029		0.059
L1		0.50			0.020	
L2		0.50			0.020	

Package information STPS3L45AF

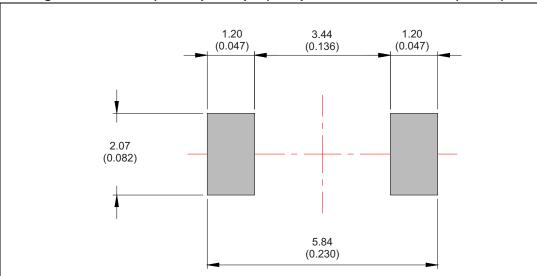


Figure 13. SMAflat (non-exposed pad) footprint dimensions in mm (inches)

# 3 Ordering information

**Table 6. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS3L45AF	F3L45	SMAflat (non-exposed pad)	0.035 g	10000	Tape and reel

## 4 Revision history

Table 7. Document revision history

Date	Revision	Description of changes	
08-Jul-2013	1	First release.	
03-Feb-2014	2	Updated Table 5, Figure 12 and Figure 13.	

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